# SILICON TRANSISTOR 2SC3810

# NPN SILICON EPITAXIAL TRANSISTOR FOR MICROWAVE AMPLIFIERS AND ULTRA HIGH SPEED SWITCHINGS INDUSTRIAL USE

# FEATURES

- The 2SC3810 is an NPN silicon epitaxial dual transistor having a large-gain-bandwidth product performance in a wide operating current range.
- Dual chips in one package can achieve high performance for differential amplifiers and current mode logic (CML) circuits.

PARAMETER	SYMBOL	RATINGS	UNIT
Collector to Base Voltage	Vсво	20	V
Collector to Emitter Voltage	Vceo	10	V
Emitter to Base Voltage	Vево	1.5	V
Collector Current	lc	65/unit	mA
Total Power Dissipation	Ρτ	240/unit	mW
Thermal Resistance (junction to case)	Rth (j-c)	90/unit	°C/W
Junction Temperature	Tj	200	°C
Storage Temperature	Tstg	-65 to +200	°C

#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

#### PACKAGE DIMENSIONS (in millimeters)







# ELECTRICAL CHARACTERISTICS (TA = 25 °C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Collector to Base Breakdown Voltage	ВУсво	$Ic = 10 \ \mu A$	20			V
Emitter to Base Breakdown Voltage	ВVево	$I_E = 10 \ \mu A, \ I_C = 0$	1.5			V
Collector to Emitter Breakdown Voltage	BVCEO	Ic = 1 mA, R <sub>BE</sub> = ∞	10			V
Collector Cut-off Current	Ісво	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0$			1.0	μA
Emitter Cut-off Current	Іево	V <sub>EB</sub> = 1 V, Ic = 0			1.0	μA
DC Current Gain	hfe	Vce = 8 V, Ic = 20 mA	50	100	250	
hfe Ratio	hFE1/hFE2 Note 1	Vce = 8 V, Ic = 20 mA	0.6		1.0	
Difference of Base to Emitter Voltage	$\varDelta$ Vbe	Vce = 8 V, Ic = 20 mA			30	mV
Gain Bandwidth Product	f⊤ <sup>Note 2</sup>	Vce = 8 V, Ic = 20 mA	7	8		GHz
Feedback Capacitance	Cre Note 3	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1.0 \text{ MHz}$		0.5	1.0	pF

**Notes 1.**  $h_{\text{FE1}}$  is the smaller  $h_{\text{FE}}$  value of the 2 transistors.

2. Measured using a single-type device (equivalent to the 2SC3604).

**3.** Measured with a 3-terminal bridge, terminals other than the collector and base of the device under test should be connected to the guard terminal of the bridge.

#### **REGARDING CLEANSING**

Cleanse the flux after soldering. Particularly, cleanse the bottom surface of the transistor so that flux does not remain. If any flux remains on the bottom surface, it may absorb moisture, resulting in short circuit among pins due to metal-migration at the metalized area of the transistor. You can use **alcohol** as a solvent.

Do not apply ultra-sonic-cleaning on this product.

## TYPICAL CHARACTERISTICS (TA = 25 °C)







[MEMO]

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Anti-radioactive design is not implemented in this product.

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